Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	190	361/41	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/13 14:38
S2	14	"6,249,410"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:22
S3	22	("4855620"   "4937700"   "5086365"   "5237395"   "5255146"   "5287241"   "5311391"   "5440162"   "5500546"   "5598313"   "5610791"   "5625280"   "5631793"   "5774318"   "5784242"   "5825603"   "5835328"   "5946175"   "5956219"   "5959488"   "5959820"   "6172383").PN.	USPAT	OR	ON	2004/09/01 13:29
S4	22	("4855620"   "4937700"   "5086365"   "5237395"   "5255146"   "5287241"   "5311391"   "5440162"   "5500546"   "5598313"   "5610791"   "5625280"   "5631793"   "5774318"   "5784242"   "5825603"   "5835328"   "5946175"   "5956219"   "5959488"   "5959820"   "6172383").PN.	USPAT	OR .	ON	2004/09/01 13:29
S5	24	"5,959,820"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 15:35
S6	814	esd same bipolar adj transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 15:36
S7	4	esd same bipolar adj transistor near (clamp clamping)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 15:38
S8	17	"4,924,339"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 15:40

S9	30	"4,994,874"	US-PGPUB;	OR	ON	2004/09/01 15:40
	30	1,55 1,67 1	USPAT; EPO; JPO; DERWENT; IBM_TDB		Oil	200 (703) 01 13.10
S10	15	"5,079,612"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 15:45
S11	4	"5,196,913"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 15:47
S12	46	"5,218,222"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 16:00
S13	23	"5,272,371"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 16:26
S14	766	361/91.1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/01 16:26
S15	0	esd same no adj power near active	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:11
S16	0	esd and no adj power near active	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:12
S17	0	esd and no adj power near (active conducting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:12
S18	0	esd and (no lack adj of ) adj power near (active conducting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:13

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S19	408	esd and power near applied	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:13
S20	288	esd and power adj applied	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:13
S21	0	esd and power adj applied near active	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:14
S22	2	esd and power adj applied near (active conductive)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:14
S23	2	esd and power adj applied near (enable enabled enabling)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:16
S24	. 0	esd and power adj applied near (enable enabled enabling) near esd	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:16
S25	0	esd and power adj (absent lack) near (enable enabled enabling)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:17
S26	0	esd and power adj (absent lack) near (operative operating)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:18
S27	0	esd same power adj (absent lack)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 10:18
S28	58	esd same power adj applied	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 12:03

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S29	33	esd and (programming program) adj circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 12:05
S30	66	esd and (programming program programmable) adj circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 12:06
S31	0	esd and (programming program programmable) adj circuit same power near applied	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 12:06
S32	0	esd and (programming program programmable) adj circuit same circuit adj assembled	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 12:06
S33	0	esd and (programming program programmable) adj circuit same circuit near assembled	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 12:07
S34	0	esd same (programming program programmable) adj circuit same circuit near assembled	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 12:08
S35	5	esd same (programming program programmable) adj circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 15:56
S36	7	("5287241"   "5369552"   "5784242"   "5959821"   "5970321"   "5991135"   "6060752").PN.	USPAT	OR	ON	2004/09/02 12:13
S37	4	("4446534"   "4823320"   "5663902"   "6028756").PN.	USPAT	OR	ON	2004/09/02 12:52
S38	3	("4412241"   "4823181"   "5151611").PN.	USPAT	OR	ON	2004/09/02 16:10
S39	25	"5341267".URPN.	USPAT	OR	ON	2004/09/02 16:12
S40	3	("4412241"   "4823181"   "5151611").PN.	USPAT	OR	ON	2004/09/02 16:20
S41	3129	361/111	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/02 17:05

S42	36	esd and threshold near (programming programmed programmable)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/09 11:56
S43	2	esd same threshold near (programming programmed programmable)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/09 10:30
544	3	("5173755"   "5400202"   "5717558").PN.	USPAT	OR	ON	2004/09/09 10:31
S45	1	"5995354".URPN.	USPAT	OR	ON	2004/09/09 10:32
S46	0	esd and threshold near (programming programmed programmable) near fuse	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/09 11:56
S47	8	esd near fuse	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/09 11:58
S48	42	esd same fuse same resistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/09 14:10
S49	0	esd same fuse near resistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/09 11:59
S50	15	"5,682,049"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/09 14:12
S51	4	("4786956"   "4941028"   "5341267"   "5498895").PN.	USPAT	OR	ON	2004/09/09 14:28
S52	4	("4786956"   "4941028"   "5341267"   "5498895").PN.	USPAT	OR	ON	2004/09/09 14:28
S53	13	"5682049".URPN.	USPAT	OR	ON	2004/09/09 14:30
S54	13	"5682049".URPN.	USPAT	OR	ON	2004/09/09 14:36
S55	74	"5,400,202"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 11:41

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S56	27	"5,341,267"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 11:43
S57	2356	fuse near (programming programmable)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 11:43
S58	161	fuse near (programming programmable) same resistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 11:44
S59	2	fuse near (programming programmable) same (resistor resistive) adj divider	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 12:00
S60	0	fuse near (resistor resistive) adj divider	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 12:01
S61	60	fuse same (resistor resistive) adj divider	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 12:02
S62	2	fuse same (resistor resistive) adj divider same programming	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/10 13:34
S63	8	("4417154"   "4446534"   "4480199"   "4499387"   "4533841"   "4592025"   "4593203"   "4605872").PN.	USPAT	OR	ON	2004/09/10 13:34
S64	3919	361/56	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2004/09/10 15:04
S65	3	"6,365,938"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:49

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S66	729	integrated near circuit and plasma near damage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:50
S67	7	integrated near circuit and plasma near damage near (protect protecting protection)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:54
S68	37	"5,760,445"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:54
S69	8	("5422507"   "5519242"   "5587598"   "5682049"   "5731600"   "6060752"   "6060753"   "6091114").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/17 15:58
S70	0	("6365938").URPN.	USPAT	OR	OFF	2005/03/17 16:01
S71	0	("6365938").URPN.	USPAT	OR	OFF	2005/03/17 16:05
S72	8	("5422507"   "5519242"   "5587598"   "5682049"   "5731600"   "6060752"   "6060753"   "6091114").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/17 16:05
S73	866	361/91.1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/03/17 16:33
S74	185	esd and (mos mosfet fet field adj effect) same (program programming programmed)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:24
S75	46	esd and (mos mosfet fet field adj effect) same (program programming programmed) and clamp	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:24
S76	2250648	esd and (mos mosfet fet field adj effect) same (program programming programmed) and clamp and third (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:24
S77	2	esd and (mos mosfet fet field adj effect) same (program programming programmed) and clamp and third near (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:26

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S78	11	esd and (mos mosfet fet field adj effect) same (program programming programmed) and third near (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:28
S79	5	esd and (mos mosfet fet field adj effect) same (program programming programmed) near (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:34
S80	0	overvoltage near (protectprotecting protectoin) and (mos mosfet fet field adj effect) same (program programming programmed) near (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:34
S81	0	overvoltage near (protect protecting protection) and (mos mosfet fet field adj effect) same (program programming programmed) near (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:34
S82	0	overvoltage near (protect protecting protection) and (mos mosfet fet field adj effect) same (program programming programmed) near (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:35
S83	0	overvoltage and (mos mosfet fet field adj effect) same (program programming programmed) near (pad terminal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 09:35